

General Description

The AL88902Q is a synchronous buck converter with internal compensation and switching frequency adjustable up to 2.5MHz. The device integrates a 120mΩ high-side power MOSFET and a 55mΩ low-side power MOSFET to provide high-efficiency DC-DC conversion.

The AL88902Q enables a continuous load current of up to 2.5A, with efficiency as high as 95% in enhanced biased. The device features current mode control operation, which enables easy loop stabilization supporting a wide range of output loading, suitable for both CV (Constant Voltage) and CC (Constant Current) applications.

The AL88902Q simplifies board layout and reduces space requirements with its high switching frequency and use of smaller size inductor and built-in MOSFET, making it ideal for power management.

The AL88902Q is available in the standard Green TSSOP-16EP package.

Applications

- Automotive infotainment
- Automotive exterior and interior LED lighting systems
- Automotive motor controls
- Automotive and industrial power systems

Key Features

- AEC-Q100 Grade1
- V_{IN} 3.8V to 60V
- Wide V_{OUT} Range: 0.8V to near 100% of V_{IN}
- V_{OUT} 1% Accuracy
- V_{FB} Adjustable through SS/TR Pin
- Synchronous Rectification > 95% Efficiency @12V
 - High-Side (120mΩ) Power MOSFET
 - Low-Side (55mΩ) Power MOSFETs
- Low Quiescent Current 43μA
- Switching Frequency 300kHz to 2.5MHz
- Force PWM or PFM Mode through MYSNC
- Synchronization to External Clock
- Programmable Startup Control
 - Startup with Pre-Biased Output
 - External Soft-Start with Tracking
 - High Voltage Enable Pin with High Precision
- Protection and Diagnosis Functions
 - Power Good (PG) Detection
 - Thermal Shutdown Protection
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The AL88902Q is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.**

<https://www.diodes.com/quality/product-definitions/>

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. Automotive products are AEC-Q100 qualified and are PPAP capable. Refer to <https://www.diodes.com/quality/>.

Evaluation Board

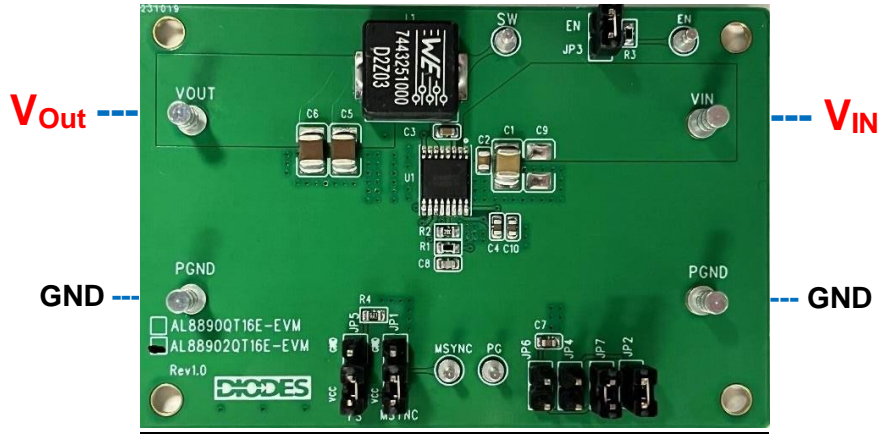


Figure 1: AL88902QT16E EVM Top View

Board Layout

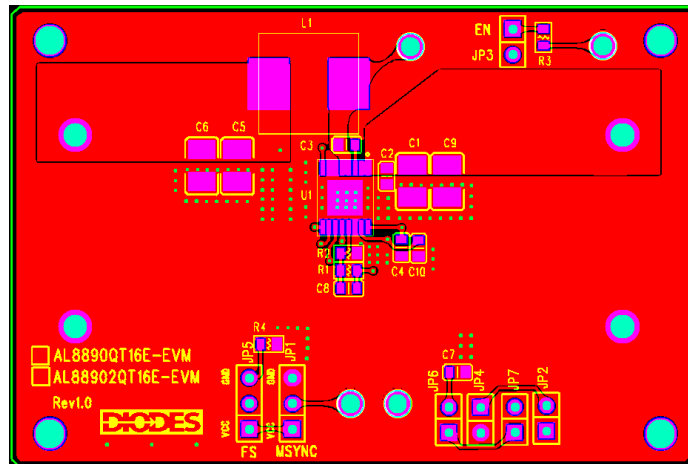


Figure 2: PCB Top Layer (Top View)

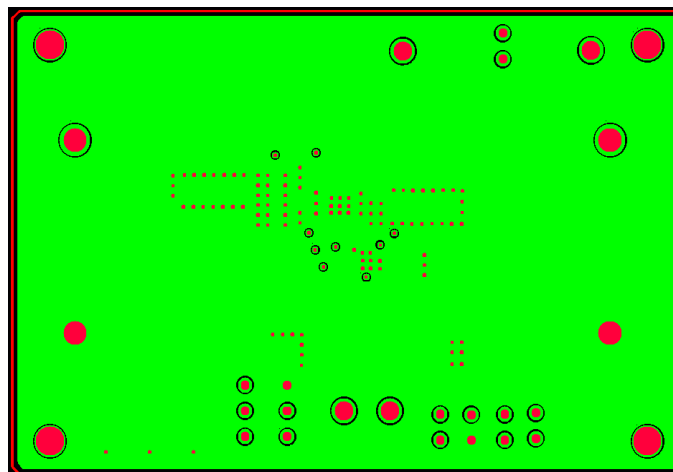


Figure 3: PCB Second Layer (Top View)

Board Layout (continued)

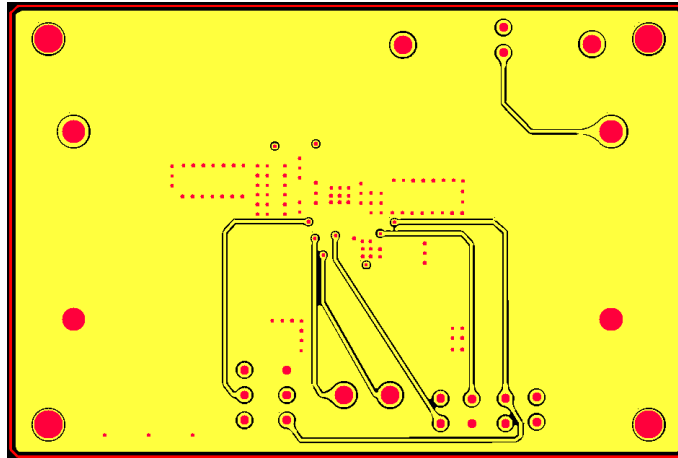


Figure 4: PCB Third Layer (Top View)

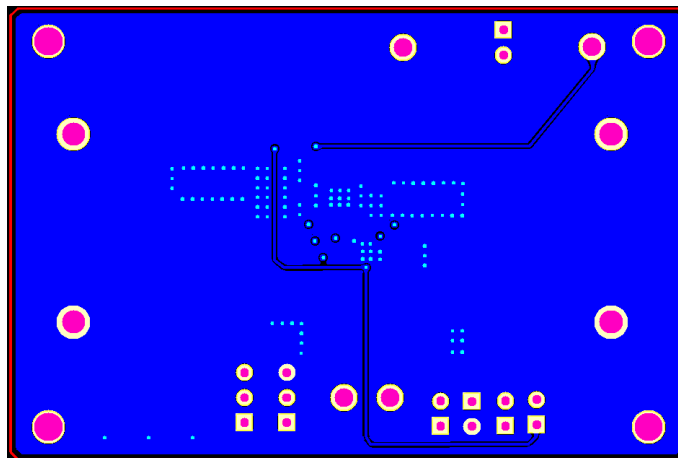


Figure 5: PCB Bottom Layer (Top View)

Quick Start Guide

The AL88902QT16E-EVM board has a simple layout and allows access to the appropriate signals through test points. To evaluate the performance of the AL88902Q, follow the procedure below:

1. Insert jumpers to configure the EVM board setting as described in the Application Information sections of the device datasheet.
2. Use jumper JP3 (100KΩ to VIN) set device enabled or JP2 (GND) to disable the device.
3. Remove jumpers JP2 and JP3 and connect external voltage source on EN pin directly.
4. Use jumper JP5 to set FS to default 500KHz (VCC) or 2.5MHz (GND).
5. Use jumper JP1 to set MSYNC to forced PWM (VCC) or PFM (GND) operation.
6. Remove jumper JP1 and force an external clock source on MSYNC pin for synchronization with positive edge trigger and PWM.
7. Use jumper JP6 for default external soft start (C7) of 2ms.
8. Remove jumper JP6 and use jumper JP7 (VCC) for internal soft start of 1.7ms.
9. Use jumper JP8 to connect BIAS pin to PGND.
10. Use jumper JP9 to connect BIAS pin to VOUT.
11. Remove JP8 and JP9 and connect an external voltage source on BIAS pin (<15V).
12. Connect a 12V power supply between the VIN and PGND terminals. Make sure the power supply is turned off.
13. Connect an adjustable current or resistive load to the VOUT and PGND terminals.
14. Turn on the power supply. Do not turn on the power supply until all connections are completed and fully checked.
15. The EVM board should now power up with a 5V output voltage.
16. Increase the load current and observe the output voltage change.
17. Check for the stable operation of the SW and VOUT signal on the oscilloscope.
18. Measure the switching frequency on SW probe jack in the EVM board.
19. Measure the output ripple on the VOUT probe jack in the EVM board.

Measurement/Performance Guidelines

When measuring the output voltage ripple, maintain the shortest possible ground lengths on the oscilloscope probe. Long ground leads can erroneously inject high frequency noise into the measured ripple.

Evaluation Board Schematic

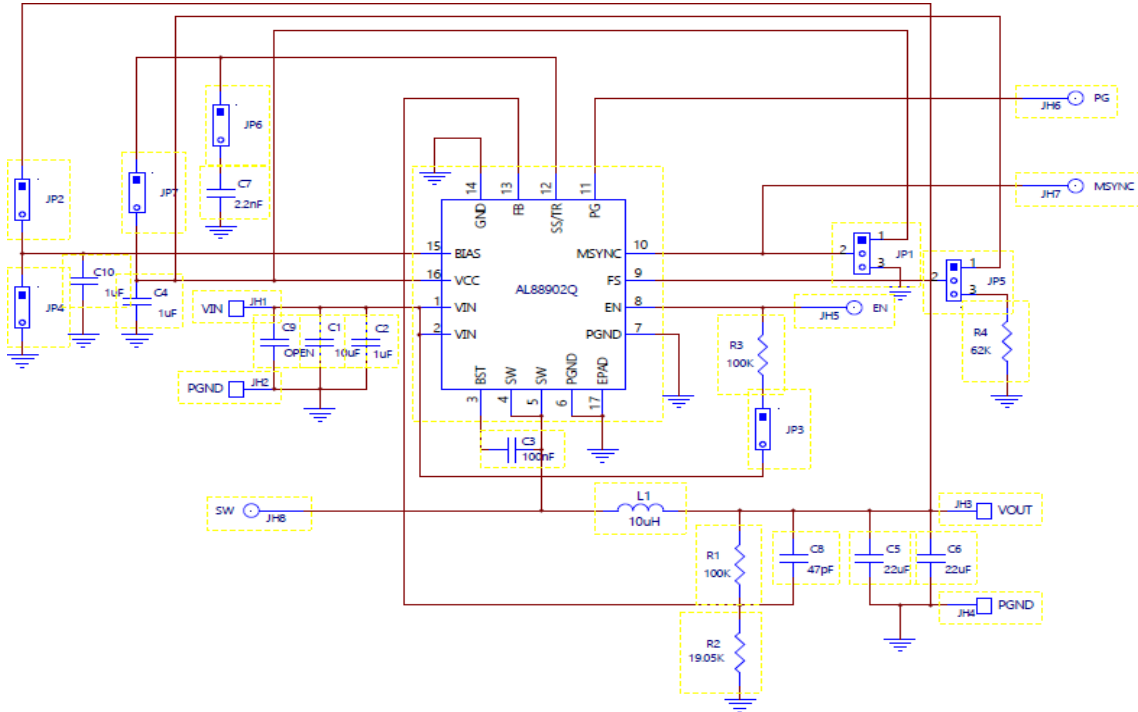
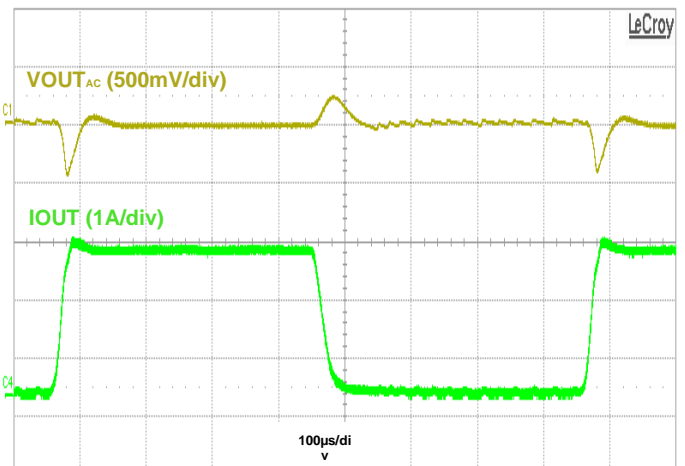
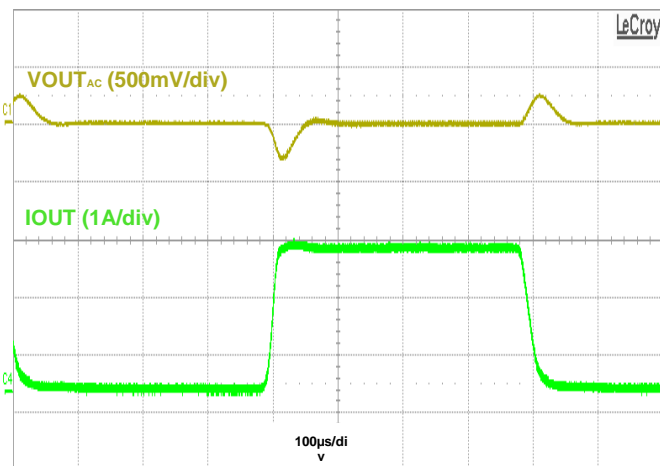
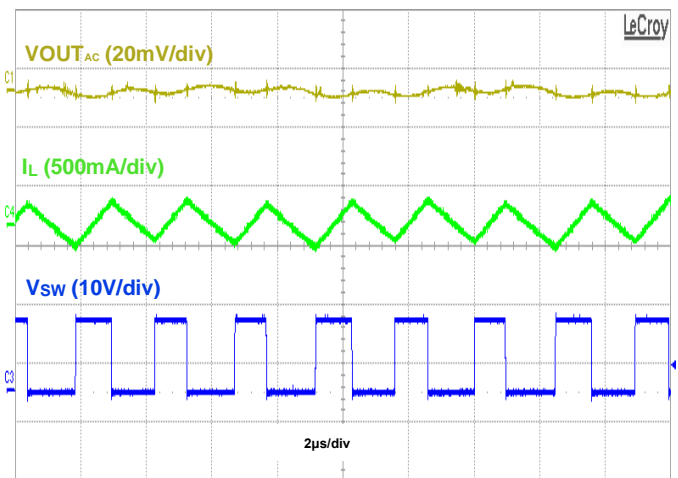
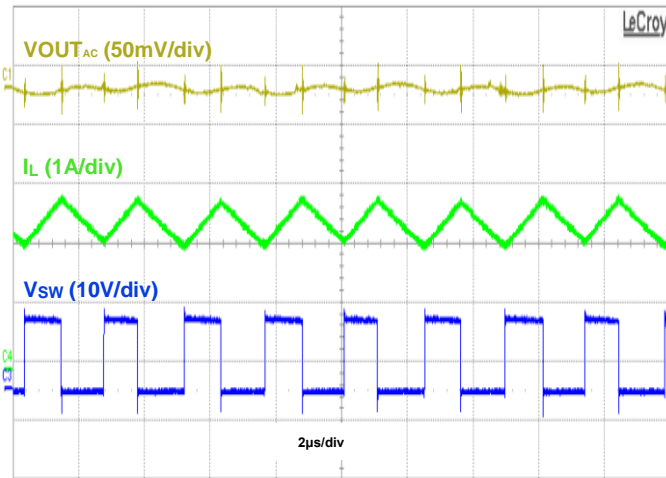
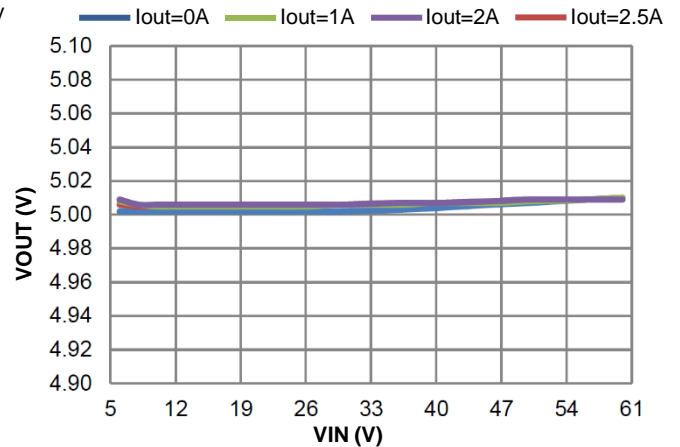
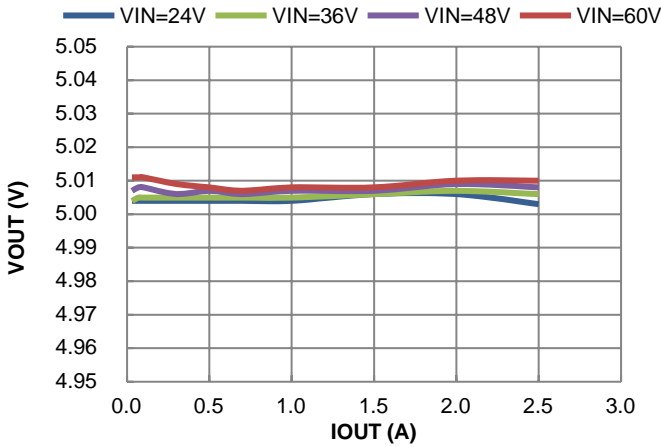


Figure 6: Schematic Circuit

Bill of Materials

Qty	Ref	Value	Description	Package	Manufacturer	Manufacturer P/N
1	C1	10uF	Ceramic Capacitor 100V	1210	Murata	GRM32EC72A106KE05L
1	C2	1uF	Ceramic Capacitor 100V X5R 20%	805	Murata	GRJ21BC72A105KE11L
1	C3	100nF	Ceramic Capacitor 50V X7R 10%	603	TDK	CGA3E2X7R1H104KTOYON
2	C4, C10	1uF	Ceramic Capacitor 25V X7R 10%	603	Taiyo Yuden	963-TMK107B7105KA-T
2	C5, C6	22uF	Ceramic Capacitor 25V X5R	1210	Taiyo Yuden	TMK325BJ226MM-T
1	C7	2.2nF	Ceramic Capacitor 50V X7R 10%	603	AVX	0603C222KAT2A
1	C8	47pF	Ceramic Capacitor 100V X7R 20%	603	Kemet	C0603C470K1RACTU
2	R1, R3	100KΩ	Film Resistor	603	Panasonic	ERJ-3EKF1003V
1	R2	19.1KΩ	Film Resistor	603	Yageo	AC0603FR-0719K1L
1	R4	62KΩ	Film Resistor	603	Yageo	AC0603FR-1362KL
1	L1	10uH	DCR=16.3mΩ, Isat=7.2A	10.5x10.5x4.7mm	Würth	7443251000
5	JP2, 3, 4, 6 7		PCB Header, 40 POS	1X2	3M	2340-611TG
2	JP1 & 5		PCB Header, 40 POS	1X3	3M	2340-611TG
4	PG, MSYNC, SW & EN		PCB Turrent Term 0.082"	0.082"	Keystone	1573-2
4	VIN, VOUT & PGNDx2		PCB Turrent Term 0.094"X1/16	0.094"	Keystone	1598-2
1	AL88902Q		IC	TSSOP-16EP	Diodes	Customer Provides

Typical Performance Characteristics ($T_A = +25^\circ\text{C}$, $V_{IN} = 12\text{V}$, $V_{OUT} = 5\text{V}$, $f_{sw} = 400\text{kHz}$)



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